

BLP8G21S-160PV

Power LDMOS transistor

Rev. 1 — 8 August 2013

Objective data sheet

1. Product profile

1.1 General description

160 W LDMOS transistor for base station applications at frequencies from 1880 MHz to 2025 MHz.

Table 1. Typical performance

Typical RF performance of half device at $T_{case} = 25\text{ °C}$ in a common source class-AB production test circuit.

Test signal	f (MHz)	I_{Dq} (mA)	V_{DS} (V)	$P_{L(AV)}$ (W)	G_p (dB)	η_D (%)	ACPR (dBc)
2-carrier W-CDMA	1880 to 1920	600	28	20	17.5	30	-32 [1]

[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing = 5 MHz.

1.2 Features and benefits

- Designed for broadband operation (1880 MHz to 2025 MHz)
- Decoupling leads to enable improved video bandwidth
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Internally matched for ease of use
- High power gain
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

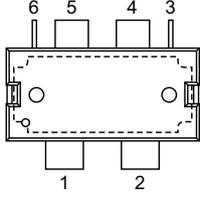
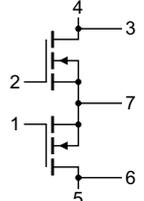
1.3 Applications

- RF power amplifiers for base station and multi-carrier applications in the 1880 MHz to 2025 MHz frequency range



2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1, 2	gate		
3	decoupling lead		
4, 5	drain		
6	decoupling lead		
7	source		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLP8G21S-160PV	HSOP6F	plastic, heatsink small outline package; 6 leads (flat)	SOT1221-1

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-case)}$	thermal resistance from junction to case	$T_{case} = 80\text{ °C};$ $P_L = <td> W$	<td>	K/W

6. Characteristics

Table 6. DC characteristics

$T_j = 25\text{ °C}$ per section, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 1.25\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 125\text{ mA}$	1.4	<td>	2.4	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 28\text{ V}$	-	-	1.4	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$	-	<td>	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	140	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 125\text{ mA}$	-	<td>	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 4.375\text{ A}$	-	<td>	-	Ω

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing = 5 MHz; 3GPP test model 1; 64 DPCH; $f_1 = 1882.5\text{ MHz}; f_2 = 1887.5\text{ MHz}; f_3 = 1912.5\text{ MHz}; f_4 = 1917.5\text{ MHz}$; RF performance of half device at $V_{DS} = 28\text{ V}; I_{Dq} = 600\text{ mA}; T_{case} = 25\text{ °C}$; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$P_{L(AV)} = 20\text{ W}$	<td>	17.5	-	dB
η_D	drain efficiency	$P_{L(AV)} = 20\text{ W}$	<td>	30	-	%
RL_{in}	input return loss	$P_{L(AV)} = 20\text{ W}$	-	-10	<td>	dB
ACPR	adjacent channel power ratio	$P_{L(AV)} = 20\text{ W}$	-	-32	<td>	dBc

7. Application information

7.1 Ruggedness in class-AB operation

The BLP8G21S-160PV is capable of withstanding a load mismatch corresponding to $V_{SWR} = 10 : 1$ through all phases under the following conditions: half device; $V_{DS} = 28\text{ V}; I_{Dq} = 600\text{ mA}; P_L = 80\text{ W (CW)}; f = 1880\text{ MHz}$.

8. Package outline

HSOP6F: plastic, heatsink small outline package; 6 leads(flat)

SOT1221-1

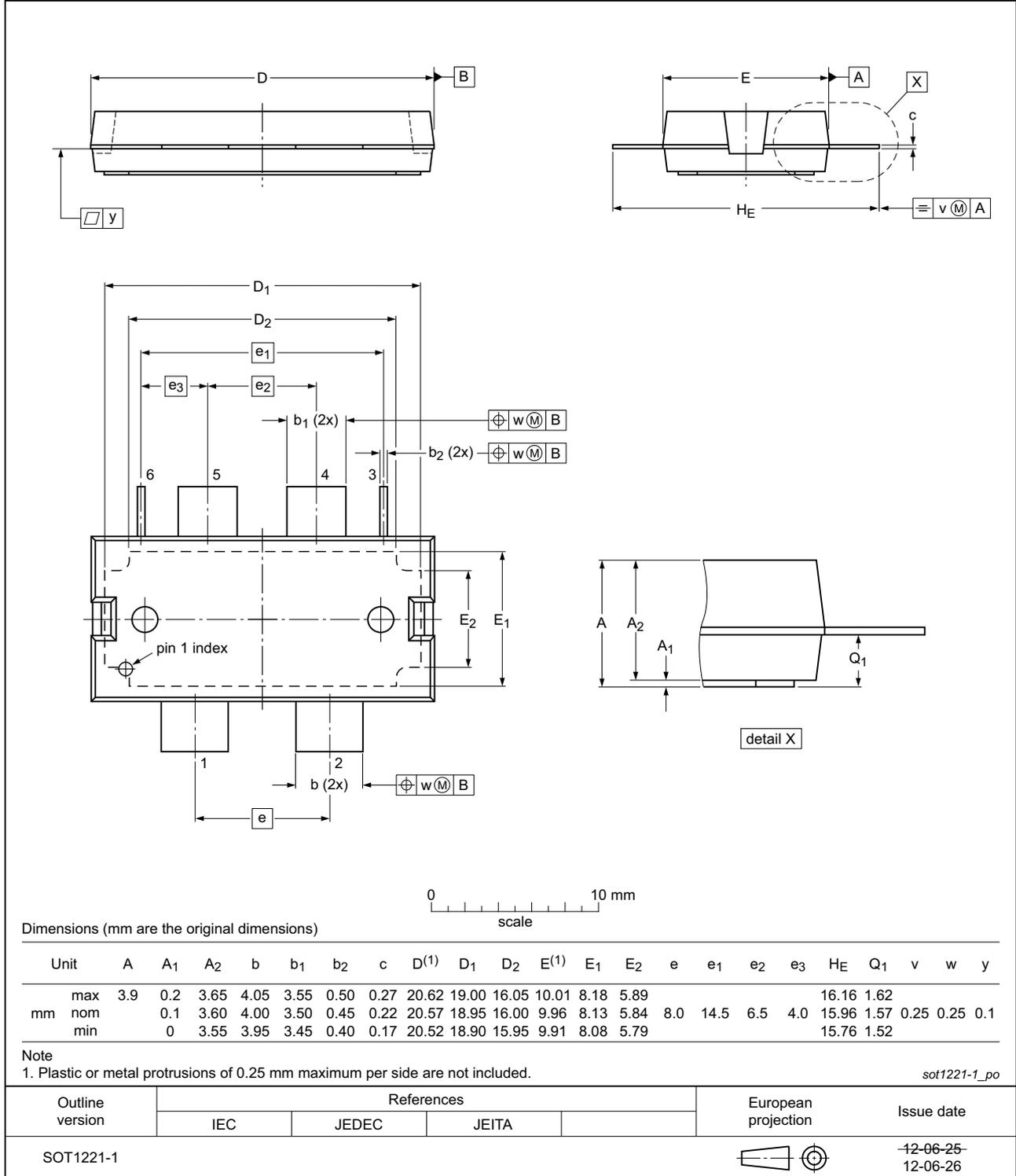


Fig 1. Package outline SOT1221-1 (HSOP6F)

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 8. Abbreviations

Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
PAR	Peak-to-Average Ratio
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP8G21S-160PV v.1	20130808	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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14. Contents

1 Product profile 1

1.1 General description 1

1.2 Features and benefits 1

1.3 Applications 1

2 Pinning information 2

3 Ordering information 2

4 Limiting values 2

5 Thermal characteristics 2

6 Characteristics 3

7 Application information 3

7.1 Ruggedness in class-AB operation 3

8 Package outline 4

9 Handling information 5

10 Abbreviations 5

11 Revision history 5

12 Legal information 6

12.1 Data sheet status 6

12.2 Definitions 6

12.3 Disclaimers 6

12.4 Trademarks 7

13 Contact information 7

14 Contents 8

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